

Abstract Submitted
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Coherent THz-wave emission from voltage- and number-controlled intrinsic Josephson junctions in $\text{Bi}_2\text{Sr}_2\text{CaCu}_2\text{O}_{8+\delta}$ ¹ MANABU TSUJIMOTO, RYO NAKAYAMA, NAOKI ORITA, TAKASHI KOIKE, KOTA DEGUCHI, KAVEH DELFANAZARI, TAKASHI YAMAMOTO, TAKANARI KASHIWAGI, HIDETOSHI MINAMI, MASASHI TACHIKI, KAZUO KADOWAKI, University of Tsukuba — Intense and coherent terahertz electromagnetic wave (THz-wave) emission from the intrinsic Josephson junctions (IJJs) in single crystalline high- T_c superconductor $\text{Bi}_2\text{Sr}_2\text{CaCu}_2\text{O}_{8+\delta}$ (Bi-2212) was reported in 2007 [L. Ozyuzer *et al.*, *Science* **318**, (2007) 1291.]. In the present work, we demonstrate the relationship between the bias condition and the resonance state by controlling both the applied voltage, V , and the number of resistive junctions, N . We directly observed that if N junctions are in resistive state, the resonance frequency, f_J , varies in accordance with the ac-Josephson relation; $f_J = (2|e|/h)V/N$, although frequency f_J has previously been thought to be uniquely determined by the geometrical condition due to the cavity resonance effect [M. Tsujimoto *et al.*, *Phys. Rev. Lett.* **105**, (2010) 037005.]. We also found that the emission intensity varies as a function of both f_J and N .

¹CREST-JST, WPI-MANA, Strategic Initiative A (University of Tsukuba)

Manabu Tsujimoto

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